SEMICONDUCTOR DEVICES

Test Paper-III

MAX MARKS: 30 TIME: 90Mts SI. No. QUESTION **ANSWER PAGE** MARKS Why Si and GaAs are preferred materials for solar cells? 3 1 Page:490 2 What must be the minimum band gap for a semiconductor to be used for the fabrication of visible LEDs? Page:488 1 3 Give the V-I characteristic curve of a a. Solarcell. 2 Page:489 b. Photo diode Page:487 What is an n-p-n transistor give the symbol representing the same. Give the biasing 4 condition of the transistor with a suitable circuit diagram. Also give the relation 3 between the base current, collect current and emitter current. 5 Explain why base region is thin, emitter is heavily doped when compared to the collector and the base in case of a transistor. 2 6 What is a pnp transistor? Give the symbol representing the same. Also give the biasing condition of the transistor with a suitable circuit diagram. 3 7 Explain how an npn transistor works as a CE amplifier with a suitable circuit diagram by giving the input and output waveforms. Page:498 3 8 Give the circuit arrangement for studying the input and output characteristics of npn transistor in CE configuration Also give the input and output characteristic 3 curves of CE Configuration. Page:494 9 Define the following terms for a transistor in CE Mode 3 a. Input resistance b. Output resistance c. Current amplification factor For a transistor amplifier, the audio signal voltage across the collector resistance of 10 $2.0k\Omega$ is 2.0 V. Suppose the current amplification factor of the transistor is 100, what 3 should be the value of RB in series with VBB supply of 2.0V if the dc base current has

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	to be 10 times the signal current? Also calculate the dc drop across the collector		
	resistance.	Page:500	
11	Give any two differences between an analog signal and a digital signal	Page:502	2
12	Draw the input and output waveforms of AND gate.	Page:504	1
13	What is a NAND gate Give the Truth table and logic symbol of the same?	Page:504	1